L497

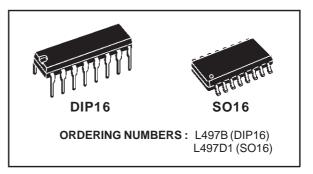
# SGS-THOMSON MICROELECTRONICS

## HALL EFFECT PICKUP IGNITION CONTROLLER

- DIRECT DRIVING OF THE EXTERNAL POWER DARLINGTON
- COIL CURRENT CHARGING ANGLE (dwell) CONTROL
- PROGRAMME COIL CURRENT PEAK LIMITA-TION
- PROGRAMMABLE DWELL RECOVERY TIME WHEN 94 % NOMINAL CURRENT NOT REACHED
- RPM OUTPUT
- PERMANENT CONDUCTION PROTECTION
- OVERVOLTAGE PROTECTION FOR EXTER-NAL DARLINGTON
- INTERNAL SUPPLY ZENER
- REVERSE BATTERY PROTECTION

### DESCRIPTION

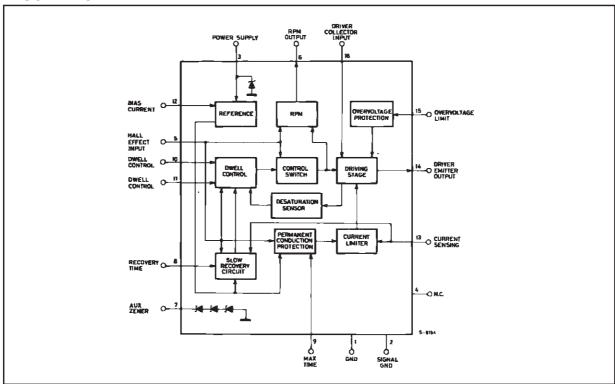
The L497 is an integrated electronic ignition controller for breakerless ignition systems using Hall effect sensors.



The device drives an NPN external darlington to control the coil current providing the required stored energy with low dissipation.

A special feature of the L497 is the programmable time for the recovery of the correct dwell ratio  $T_d/T$  when the coil peak current fails to reach 94 % of the nominal value. In this way only one spark may have an energy less than 94 % of the nominal one during fast acceleration or cold starts.

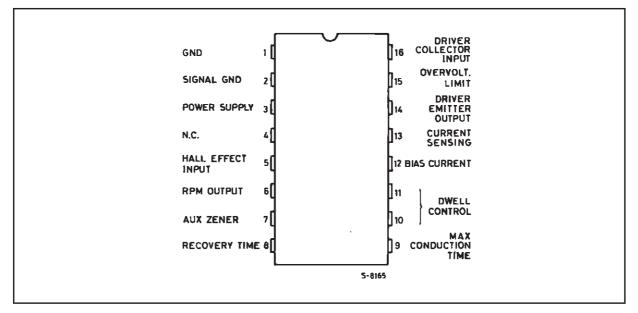
## **BLOCK DIAGRAM**



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
I <sub>3</sub>	D.C. Supply current Transient Supply Current (t <sub>f</sub> fall time constant = 100ms)	200 800	mA mA
$V_3$	Supply Voltage	Int. Limited to Vz <sub>3</sub>	
V <sub>6</sub>	RPM Voltage	28	V
I <sub>16</sub>	D.C. Driver Collector Current Pulse " "(t <= 3ms)	300 600	mA mA
V <sub>16</sub>	Driver Collector Voltage	28	V
I <sub>7</sub>	Auxiliary Zener Current	40	mA
I <sub>15</sub>	D.C. Overvoltage Zener Current Pulse " " $t_{fall} = 300 \mu s$ , $tr_{ep}$ Repetition Time > = 3ms	15 35	mA mA
V <sub>R</sub>	Reverse Battery Voltage if Application Circuit of Fig. 4 is used	- 16	V
T <sub>j</sub> , T <sub>stg</sub>	Junction and StorageTemperature Range	- 55 to 150	°C
P <sub>tot</sub>	Power Dissipation at T <sub>aluminia</sub> = 90 °C for SO-16 T <sub>amb</sub> = 90 °C for DIP-16	1.2 0.65	W W

### **PIN CONNECTION** (top view)



#### THERMAL DATA

Symbol	Parameter		Value	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient for DIP-16	Max	90	°C/W
R <sub>th j-alumin</sub> (*)	Thermal Resistance Junction-alumina for SO-16	Max	50	°C/W

(\*) Thermal resistance junction-aluminia with the device soldered on the middle of an aluminia supporting substrate mesuring 15 x 20 ; 0.65 mm thickness.



## PIN FUNCTIONS (refer to fig. 4)

N°	Name	Function
1	GND	This pin must be connected to ground.
2	SIGNAL GND	This pin must be connected to ground.
3	POWER SUPPLY	Supply Voltage Input. An internal 7.5 V (typ) zener zener limits the voltage at this pin. The external resistor $R_5$ limits the current through the zener for high supply voltages.
4	N.C.	This pin must be connected to ground or left open.
5	HALL-EFFECT INPUT	Hall-effect Pickup Signal Input. This input is dwell control circuit output in order to enable the current driving into the coil. The spark occurs at the high-to-low transition of the hall-effect pickup signal. Furthermore this input signal enables the slow recovery and permanent conduction protection circuits. The input signal, supplied by the open collector output stage of the Hall effect sensor, has a duty-cycle typically about 70 %. V <sub>5</sub> is internally clamped to V <sub>3</sub> and ground by diodes
6	RPM OUTPUT	Open collector output which is at a low level when current flows in the ignition coil. For high voltages protection of this output, connection to the pin 7 zener is recommended. In this situation $R_8$ must limit the zener current, too, and $R_1$ limits pin 6 current if RPM module pad is accidentally connected to $V_S$ .
7	AUX. ZENER	A 21 V (typ) General Purpose Zener. Its current must be limited by an external resistor.
8	RECOVERY TIME	A capacitor connected between this pin and ground sets the slope of the dwell time variation as it rises from zero to the correct value. This occurs after the detection of $I_{coll} \leq 94~\%~I_{nom}$ , just before the low transition of the hall-effect signal pulse. The duration of the slow recovery is given by : $t_{src}$ = 12,9 R <sub>7</sub> C <sub>src</sub> (ms) where R <sub>7</sub> is the biasing resistor at pin 12 (in K\Omega) and C <sub>src</sub> is the delay capacitor at pin 8 (in $\mu F$ ).
9	MAX CONDUCTION TIME	A capacitor connected between this pin and ground determines the intervention delay of the permanent conduction protection. After this delay time the coil current is slowly reduced to zero. Delay Time T <sub>p</sub> is given by : T <sub>p</sub> =16 C <sub>p</sub> R <sub>7</sub> (ms) where R <sub>7</sub> is the biasing resistor at pin 12 (in KΩ) and C <sub>P</sub> is the delay capacitor at pin 9 (in $\mu$ F).
10	DWELL CONTROL TIMER	A capacitor $C_T$ connected between this pin and ground is charged when the HAII effect output is High and is discharged at the High to Low transition of the HaII effect signal. The recommended value is 100 nF using a 62 K $\Omega$ resistor at pin 12.
11	DWELL CONTROL	The average voltage on the capacitor CW connected between this pin and ground depends on the motor speed and the voltage supply. The comparison between V <sub>CW</sub> and V <sub>CT</sub> voltage determines the timing for the dwell control. For the optimized operation of the device C <sub>T</sub> = C <sub>W</sub> ; the recommended value is 100 nF using a 62 K $\Omega$ resistor at pin 12.
12	BIAS CURRENT	A resistor connected between this pin and ground sets the internal current used to drive the external capacitors of the dwell control (pin 10 and 11) permanent conduction protection (pin 9) and slow recovery time (pin 8). The recommended value is $62 \text{ K}\Omega$ .
13	CURRENT SENSING	Connection for the Coil Current Limitation. The current is measured on the sensing resitor $R_S$ and taken through the divider $R_{10}/R_{11}$ . The current limitation value is given by : $I_{sens} = 0.32 \cdot \frac{R_{10} + R_{11}}{R_S \cdot R_{11}}$



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## PIN FUNCTIONS (continued)

N°	Name	Function
14	DRIVER EMITTER OUTPUT	Current Driver for the External Darlington. To ensure stability and precision of $T_{desat} C_c$ and $R_9$ must be used. Recommended value for $R_9$ is 2 K $\Omega$ in order not to change the open loop gain of the system. R <sub>c</sub> may be added to C <sub>c</sub> to obtain greater flexibility in various application situations. C <sub>c</sub> and R <sub>c</sub> values ranges are 1 to 100 nF and 5 to 30 K $\Omega$ depending on the external darlington type.
15	OVERVOLTAGE LIMIT	The darlington is protected against overvoltage by means of an internal zener available at this pin and connected to pin 14. The internal divider R <sub>3</sub> /R <sub>2</sub> defines the limitation value given by : $V_{ovp} = \left(\frac{22.5}{R_3} + 5.10^{-3}\right)R_2 + 22.5$
16	DRIVER COLLECTOR INPUT	The collector current of the internal driver which drives the external darlington is supplied through this pin. Then the external resistor $R_6$ limits the maximum current supplied to the base of the external darlington.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>3</sub>	Min Op. Voltage		3.5			V
l <sub>3</sub>	Supply Current	$V_3 = 6 V$ $V_3 = 4 V$	5 7	18	25 13	mA mA
Vs	Voltage Supply				28	V
$V_{Z3}$	Supply Clamping Zener Voltage	I <sub>Z3</sub> = 70 mA	6.8	7.5	8.2	V
$V_5$	Input Voltage	Low Status High Status	2.5		0.6	V V
$I_5$	Input Current	$V_5 = LOW$	- 400		- 50	μA
V <sub>16-14</sub>	Darlington Driver Sat. Current	I <sub>14</sub> = 50 mA I <sub>14</sub> = 180 mA			0.5 0.9	V V
V <sub>SENS</sub>	Current Limit. Sensing Voltage	V <sub>S</sub> = 6 to 16 V	260	320	370	mV
I <sub>11C</sub>	C <sub>W</sub> Charge Current	$V_{S} = 5.3 \text{ to } 16V$ $V_{11} = 0.5V$ T = 10  to  33ms	- 11.0	- 9.3	- 7.8	μA
I <sub>11D</sub>	CW Charge Current	V <sub>S</sub> = 5.3 to 16V V <sub>11</sub> = 0.5V T = 10 to 33ms	0.5	0.7	1.0	μA
I <sub>11C</sub> / I <sub>11D</sub>		VS = 5.3 to 16V V <sub>11</sub> = 0.5V T = 10 to 33ms See Note 1	7.8		22.0	
I <sub>SRC</sub> I <sub>SENSE</sub>	Percentage of Output Current Determining the Slow Recovery Control Start (fig. 2), note 1		90	94	98.5	%
T <sub>SRC</sub>	Duration of Altered Small Contr. Ratio after SRC Function Start (fig. 2)	C <sub>SRC</sub> = 1 μF R <sub>7</sub> = 62 KΩ		0.8		S
V <sub>Z15</sub>	External Darlington over V Prot. Zener Voltage	I <sub>15</sub> = 5 mA I <sub>15</sub> = 2 mA	19 18	22.5 21.5	26 25	V V
T <sub>P</sub>	Permanent Conduction Time	$V_5 = High$ $C_P = 1\mu F$ $R_7 = 62K\Omega$	0.4	1.1	1.8	S

**ELECTRICAL CHARACTERISTICS** (V<sub>S</sub> = 14.4 V,  $-40 \degree C < T_j < 125 \degree C$  unless otherwise specified)



## ELECTRICAL CHARACTERISTICS (continued)

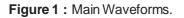
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>6SAT</sub>		I <sub>6</sub> = 18.5 mA			0.5	V
		I <sub>6</sub> = 25 mA			0.8	V
I <sub>6 leak</sub>	RPM Output Leakage Current	V <sub>S</sub> = 20 V			50	μA
V <sub>Z7</sub>	Auxiliary Zener Voltage	I <sub>7</sub> = 20 mA	19		27	V
V <sub>12</sub>	Reference Voltage		1.20	1.25	1.30	V

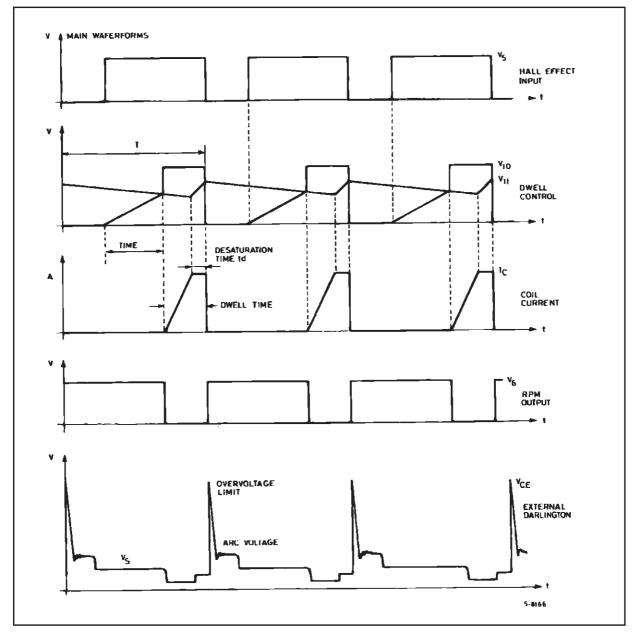
**Notes :** 1. td/t desaturation ratio is given by:  $\frac{td}{T}$ 1

 $=\frac{1}{1+I_{11C}/I_{11D}}$ 

2.  $I_{sense} = I_{coil}$  when the external Darlington is in the active region.

## **APPLICATION INFORMATION**





SGS-THOMSON MICROELECTRONICS

### DWELL ANGLE CONTROL

The dwell angle control circuit calculates the conduction time D for the output transistor in relation to the speed of rotation, to the supply voltage and to the characteristics of the coil.

On the negative edge of the Hall-effect input signal the capacitor C<sub>W</sub> begins discharging with a constant current I<sub>11D</sub>. When the set peak value of the coil current is reached, this capacitor charges with a constant current I<sub>11C</sub> = 13.3 x I<sub>11D</sub>, and the coil current is kept constant by desaturation of the driven stage and the external darlington.

The capacitor  $C_T$  starts charging on the positive.edge of the Hall-effect input signal with a constant current  $I_{10C}$ . The dwell angle, and consequently the starting point of the coil current conduction, is decided by the comparison between  $V_{10}$  and  $V_{11}$ .

A positive hysteresis is added to the dwell comparator to avoid spurious effects and  $C_{\rm T}$  is rapidly discharged on the negative edge of Hall-effects input signal.

In this way the average voltage on  $C_W$  increases if the motor speed decreases and viceversa in order  $% \mathcal{C}_W$ 

to maintain constant the ratio  $\frac{t_d}{T}$  at any motor speed.

 $\frac{t_d}{T}$  is kept constant (and not  $\frac{D}{T} = cost$ ) to control

the power dissipation and to have sufficient time to avoid low energy sparks during acceleration.

## DESATURATION TIMES IN STATIC CONDITIONS

In static conditions and if  $C_T = C_W$  as recommended and if the values of the application circuit of fig.4 are used.

$$\frac{t_d}{T} = \frac{1}{1 + I_{11C} / I_{11D}}$$

## DESATURATION TIMES IN LOW AND HIGH FREQUENCY OPERATION

Due to the upperlimit of the voltage range of pin 11, if the components of fig.4 are used, below 10 Hz (300 RPM for a 4 cylinder engine) the OFF time reaches its maximum value (about 50 ms) and then the circuit gradually loses control of the dwell angle because D = T - 50 ms.

Over 200 Hz (6000 RPM for a 4 cylinder engine) the available time for the conduction is less than 3.5 ms.

If the used coil is 6 mH, 6A, the OFF time is reduced to zero and the circuit loses the dwell angle control.

### TRANSIENT RESPONSE

The ignition system must deliver constant energy even during the condition of acceleration and deceleration of the motor below 80Hz/s. These conditions can be simulated by means of a signal gene-rator with a linearly modulated frequency between 1 Hz and 200 Hz (this corresponds to a change between 30 and 6000 RPM for a 4 cylinders engine).

### CURRENT LIMIT

The current in the coil is monitored by measuring the  $I_{\text{sense}}$  current flowing in the sensing resistor  $R_s$  on the emitter of the external darlington.  $I_{\text{sense}}$  is given by :

When the voltage drop across Rs reaches the internal comparator threshold value the feedbackloop is activated and  $I_{\text{sense}}$  kept constant (fig.1) forcing the external darlington in the active region. In this condition :

$$I_{\text{sense}} = I_{\text{coil}}$$

When a precise peak coil current is required  $R_{s}$  must be trimmed or an auxiliary resistor divider ( $R_{10},\,R_{11})$  added :

$$\mathsf{Icpeak}(\mathsf{A}) = \frac{0.320}{\mathsf{RS}} \cdot \left(\frac{\mathsf{R10}}{\mathsf{R11}} + 1\right)$$

## SLOW RECOVERY CONTROL (fig. 2)

If Isense has not reached 94 % of the nominal value just before the negative edge of the Hall-effect input signal, the capacitor  $C_{src}$  and  $C_W$  are quickly discharged as long as the pick-up signal is "low". At the next positive transition of the input signal the load current starts immediately, producing the maximum achievable  $T_{desat}$ ; then the voltage on  $C_{SRC}$  increases linearly until the standby is reached. During this recovery time the  $C_{SRC}$  voltage is converted into a current which, substrated from the charging current of the dwell capacitor, produces a  $T_{desat}$  modulation. This means that the  $T_{desat}$  decreases slowly until its value reaches, after a time  $T_{SRC}$ , the nominal 7% value.

The time T<sub>SRC</sub> is given by:

 $T_{rsc} = 12.9 \text{ R7 } C_{SRC} \text{ (ms)}$ 

where  $R_7$  is the biasing resistor at pin 12 (in  $K\Omega$ ) and  $C_{src}$  the capacitor at pin 8 (in  $\mu F$ ).



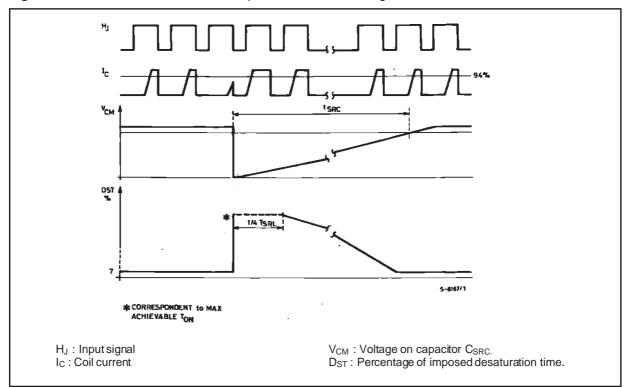
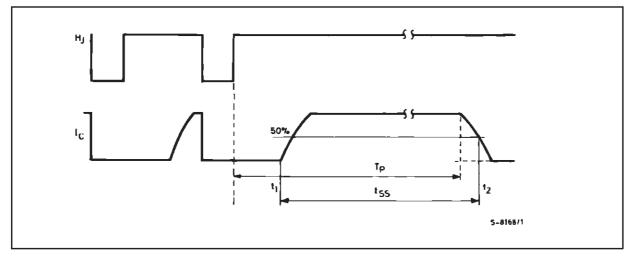


Figure 2 : SRC : Icoil Failure and Time Dependence of Active Region.





## PERMANENT CONDUCTION PROTECTION (fig. 3)

The permanent conduction protection circuit monitors the input period, charging CP with a costant current when the sensor signal is high and discharging it when the sensor signal is low. If the input remains high for a time longer than  $T_P$  the voltage across  $C_P$  reaches an internally fixed value forcing the slow decrease of coil current to zero. A slow decrease is

necessary to avoid undesired sparks. When the input signal goes low again  $C_P$  is swiftly discharged and the current control loop operates normally.

The delay time  $T_P$  is given by :  $T_P$  (sec) = 18  $C_P R_7$ Where  $R_7$  is the biasing resistor on pin 12 (in K) and Cp the delay capacitor at pin 9 (in  $\mu$ F).



### **OTHER APPLICATION NOTES**

### DUMP PROTECTION

Load dump protection must be implemented by an external zener if this function is necessary. In fig. 4  $DZ_2$  protects the driver stage, the connection between pin 6 and 7 protects the output transistor of pin 6. Moreover  $DZ_1$  protects both the power supply input (pin 3) and Hall-effect sensor.

Resistor  $R_4$  is necessary to limit  $DZ_1$  current during load dump.

#### **OVERVOLTAGE LIMITATION**

The external darlington collector voltage is sensed by the voltage divider  $R_2$ ,  $R_3$ . The voltage limitation increases rising  $R_2$  or decreasing  $R_3$ .

Due to the active circuit used, an Ro Co series net-

work is mandatory for stability during the high voltage condition.

 $R_{o} \ C_{o}$  values depend on the darlington used in the application.

Moreover the resistor  $R_{13}$  is suggested to limit the overvoltage even when supply voltage is disconnected during the high voltage condition.

### REVERSE BATTERY PROTECTION

Due to the presence of external impedance at pin 6, 3, 16, 15 L497 is protected against reverse battery voltage.

#### NEGATIVE SPIKE PROTECTION

If correct operation is requested also during short negative spikes, the diode  $D_S$  and capacitor  $C_s$  must be used.

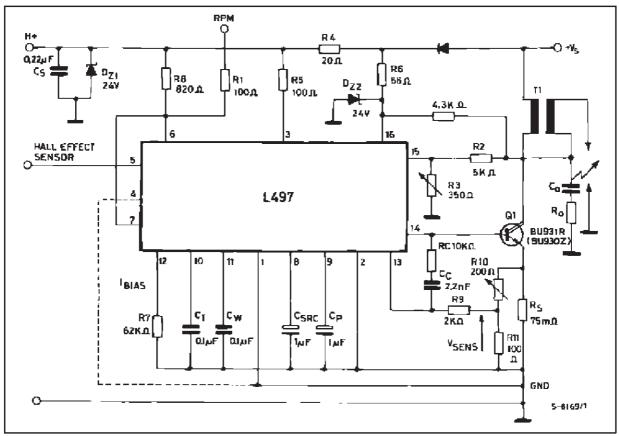
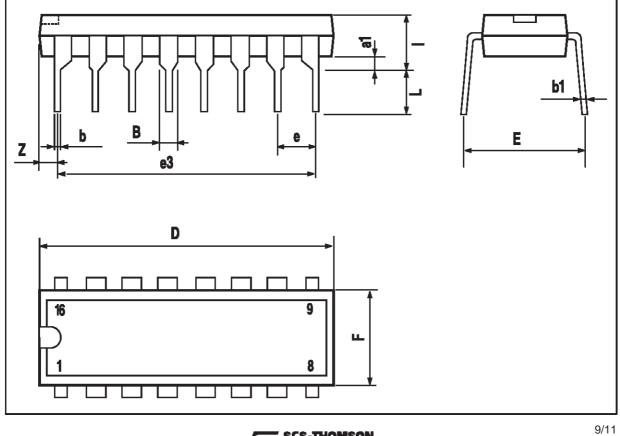


Figure 4 : Application Circuit.



### DIP16 PACKAGE MECHANICAL DATA

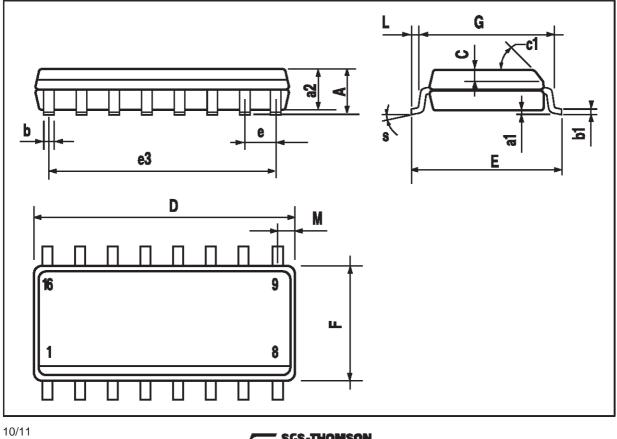
DIM.	mm			inch		
Dim	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



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### SO16 PACKAGE MECHANICAL DATA

DIM.	mm			inch			
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
A			1.75			0.069	
a1	0.1		0.2	0.004		0.008	
a2			1.6			0.063	
b	0.35		0.46	0.014		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.020		
c1			45°	(typ.)			
D	9.8		10	0.386		0.394	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		8.89			0.350		
F	3.8		4.0	0.150		0.157	
L	0.5		1.27	0.020		0.050	
М			0.62			0.024	
S			8° (r	max.)			



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## L497

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